Single 2-Input OR Gate

General Description

The ET74AUP1G32AM is a single 2-input OR Gate, which can operate from a 0.8V to 3.6V supply.
This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

Features

- Designed for 0.8V to 3.6V V_{CC} Operation
- Low Static Power Consumption; I_{CC} = 0.7μA (Maximum)
- 4mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb-Free and RoHS Compliant
- Multiple Package Options Automotive AEC-Q100 Grade 1 Qualified
  -- Ambient Temperature Range of -40°C to 125°C
  -- ESD HBM ±4KV PASS
  -- ESD CDM ±1KV PASS
  -- Latch Up Current to ±100mA PASS
- Part No. and Package Information

Part No.	Package	Packing Option	MSL
ET74AUP1G32AM	SC70-5 (1.3mm × 2.1mm)	Tape and Reel, 3K/Reel	1

Pin Configuration

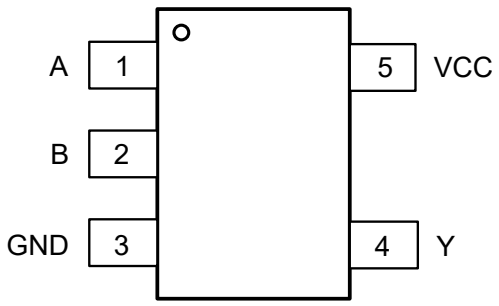


Figure1. Pin Configuration

Pin Function

Pin No.	Pin Name	Function
1	A	Input A
2	B	Input B
3	GND	Ground
4	Y	Output Y
5	VCC	Supply Voltage

Block Diagram

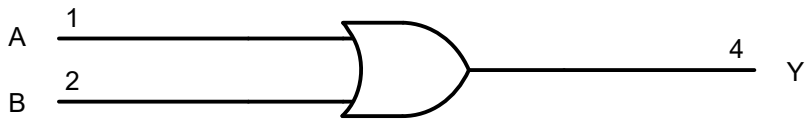


Figure2. Logic Symbol

Function Table

Input		Output
A	**B**	**Y**
L	L	L
L	H	H
H	L	H
H	H	H

Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage (VCC Pin)		-0.5 to 4.6	V
V_I	DC Input Voltage (1)		$-0.5 \le V_I \le 4.6$	V
V_O	DC Output Voltage Output in Higher or Low State		-0.5 to 4.6	V
I_{IK}	DC Input Diode Current, V_I < GND		-50	mA
I_{OK}	DC Output Diode Current, V_O < GND, V_O > V_{CC}		±50	mA
I_O	DC Output Sink Current		±20	mA
I_{CC}	DC Supply Current Per Supply Pin		+50	mA
I_{GND}	DC Ground Current Per Supply Pin		-50	mA
T_{STG}	Storage Temperature Range		-65 to 150	°C
T_L	Lead Temperature, Soldering 10 Seconds		260	°C
T_J	Max Junction Temperature		150	°C
V_{ESD}(2)	ESD Classification	Human Body Model	±4000	V
		Charged Device Model	±1000	
I_{LU}(2)	Latch Up Current Above V_{CC} and GND at 125°C		±100	mA

Stresses exceeding those listed in this table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Note1: Refer to Electrical Characteristics and Application Information for Safe Operating Area.

Note2: This device series incorporates ESD protection and is tested by the following methods:

HBM tested per AEC-Q100-002(JEDEC JS-001);

CDM tested per AEC-Q100-011(JEDEC JS-002);

Latch up Current Maximum Rating tested per AEC-Q100-004(JEDEC JESD78F).

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
$R_{\theta JA}$	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	300	°C/W
P_D	SC70-5	Power Dissipation in Still Air at 85°C	215	mW

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage Operating		0.8	3.6	V
V_I	DC Input Voltage		0	V_{CC}	V
V_O	DC Output Voltage (High or Low State)		0	V_{CC}	V
T_A	Operating Temperature Range		-40	125	°C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 0.8V to 3.6V	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied.

Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V_{CC}(V)	T_A = 25°C			-40°C ≤ T_A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	High-Level Input Voltage		0.8	0.75V_{CC}			0.70V_{CC}		V
			0.9~1.95	0.7V_{CC}			0.65V_{CC}		
			2.3~2.7	1.6			1.6		
			3.0~3.6	2.0			2.0		
V_{IL}	Low-Level Input Voltage		0.8			0.25V_{CC}		0.20V_{CC}	V
			0.9~1.95			0.3V_{CC}		0.25V_{CC}	
			2.3~2.7			0.7		0.7	
			3.0~3.6			0.9		0.9	
V_{OH}	High-Level Output Voltage	I_{OH} = -20uA	0.8~3.6	V_{CC} - 0.1			V_{CC} - 0.1		V
		I_{OH} = -1.1mA	1.1	0.82	1.02		0.77		
		I_{OH} = -1.7mA	1.4	1.11	1.32		1.03		
		I_{OH} = -1.9mA	1.65	1.32	1.58		1.30		
		I_{OH} = -2.3mA	2.3	2.05	2.24		1.97		
		I_{OH} = -3.1mA		1.9	2.22		1.85		
		I_{OH} = -2.7mA	3.0	2.72	2.95		2.67		
		I_{OH} = -4.0mA		2.6	2.92		2.55		
V_{OL}	Low-Level Output Voltage	I_{OL} = 20uA	0.8~3.6			0.1		0.1	V
		I_{OL} = 1.1mA	1.1		0.11	0.33		0.33	
		I_{OL} = 1.7mA	1.4		0.12	0.31		0.37	
		I_{OL} = 1.9mA	1.65		0.11	0.31		0.35	
		I_{OL} = 2.3mA	2.3		0.14	0.31		0.33	
		I_{OL} = 3.1mA			0.19	0.44		0.45	
		I_{OL} = 2.7mA	3.0		0.11	0.31		0.33	
		I_{OL} = 4.0mA			0.16	0.44		0.45	
I_{IN}	Input Leakage Current	V_I = V_{CC} or GND	0~3.6			±0.1		±1	uA
I_{OFF}	Power Off Leakage Current	V_I = 3.6V or V_O = 3.6V	0			±0.2		±2.0	uA
ΔI_{OFF}	Additional Power Off Leakage Current	V_I or V_O = 0V~3.6V	0~0.2			±0.2		±10	uA
I_{CC}	Quiescent Supply Current	V_I = 3.6V or GND	3.6			±0.2		±3.0	uA

Electrical Characteristics(Continued)

DC Electrical Characteristics

Symbol	Parameter	Condition	V_{CC}(V)	T_A = 25°C			-40°C ≤ T_A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
ΔI_{CC}	Additional Quiescent Supply Current	V_I = 2.7V	3.3			60		120	uA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC Electrical Characteristics

$t_r = t_f$ = 3ns

Symbol	Parameter	Condition	V_{CC}(V)	T_A = 25°C			-40°C ≤ T_A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay (Figure3 and 4)	C_L = 15pF(3)	0.8	14.5	33.9	127	10.8	352	ns
			1.2	5.5	9.5	19.3	5.1	30	
			1.5	3.8	6.0	11.8	3.3	22	
			1.8	3.0	4.5	8.9	2.6	18	
			2.5	2.1	3.0	6.3	1.8	13.2	
			3.3	1.7	2.3	5.3	1.4	11.5	
		C_L = 30pF(3)	0.8	17.6	34.3	133	13.5	382	ns
			1.2	6.7	11.3	22.2	6.2	34.5	
			1.5	4.6	7.2	13.6	4.0	24.6	
			1.8	3.6	5.4	10.2	3.1	19.5	
			2.5	2.5	3.6	7.3	2.2	13.8	
			3.3	2.0	2.8	6.0	1.7	11.5	

Note3: C_L includes probe and jig capacitance.

Capacitance Characteristics

Symbol	Parameter	Condition		Typical	Unit
C_I	Input Capacitance	V_{CC} = 3.6V, V_I = 0V or V_{CC}		2	pF
C_O	Output Capacitance	V_{CC} = 0V, V_O = GND		3	pF
C_{PD}	Power Dissipation Capacitance (4)	1MHz, V_I = 0V to V_{CC}	V_{CC} = 0.8V	7.6	pF
			V_{CC} = 1.2V	8.1	
			V_{CC} = 1.5V	8.5	
			V_{CC} = 1.8V	8.6	
			V_{CC} = 2.5V	9.0	
			V_{CC} = 3.3V	9.6	

Note4: C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

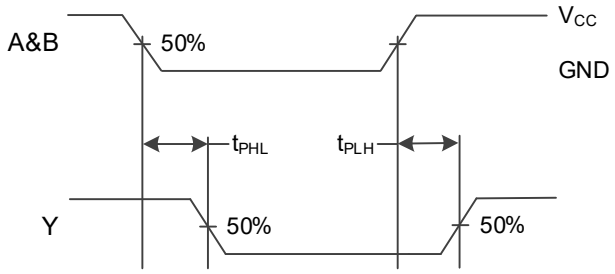
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

AC Test Circuit

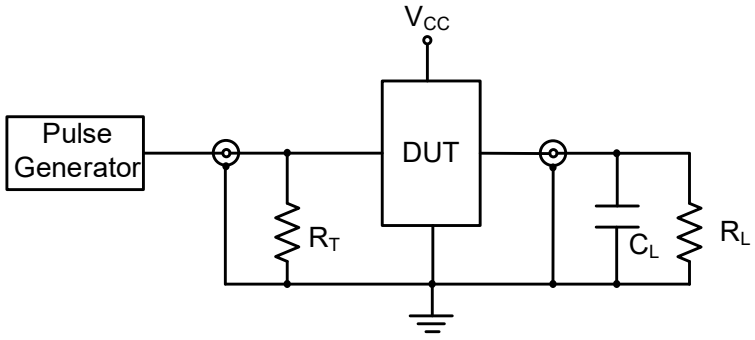


PROPAGATION DELAYS

$t_r = t_f$ = 3ns, 10% to 90%;

f = 1MHz; t_W = 500ns

Figure3. Switching Waveform

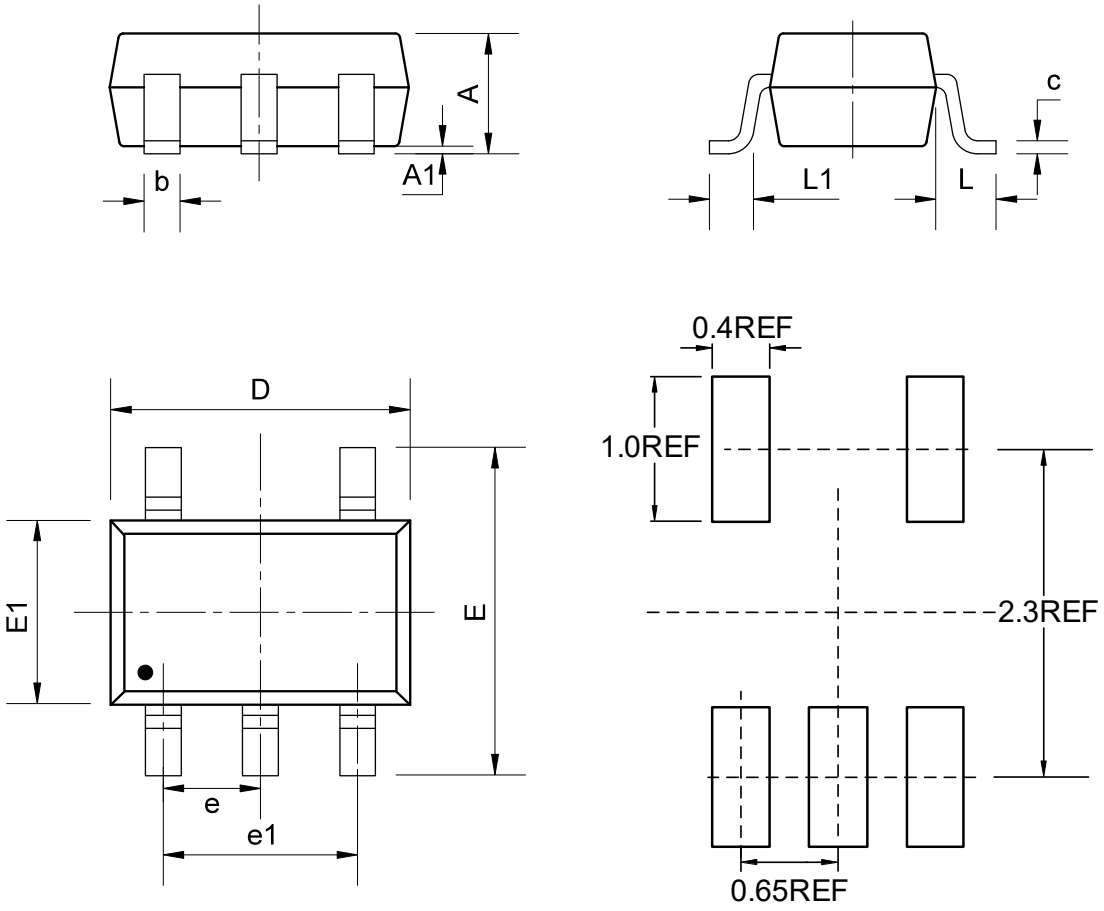


R_T = 50Ω (typ)

Figure4. Test Circuit

Package Dimension

SC70-5 (1.3mm × 2.1mm)



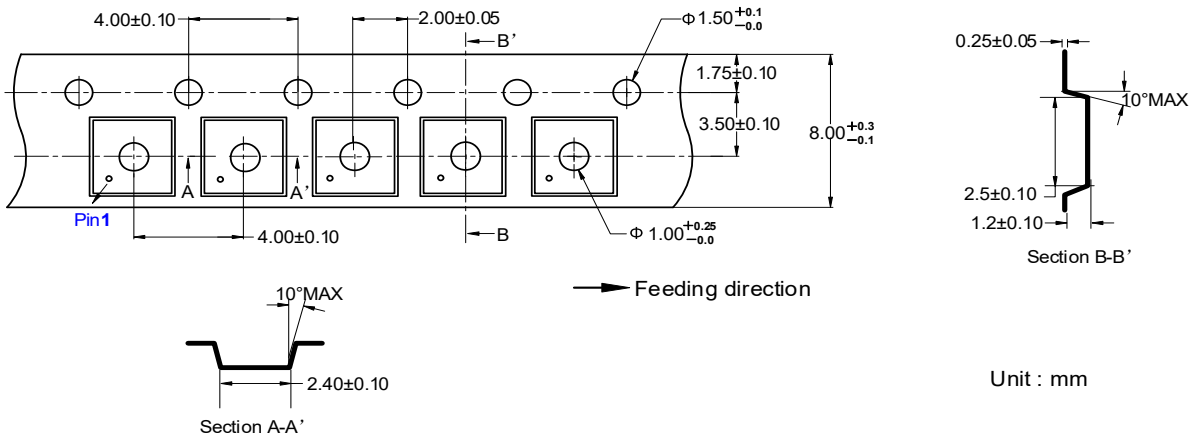
COMMON DIMENSIONS

(Unit: mm)

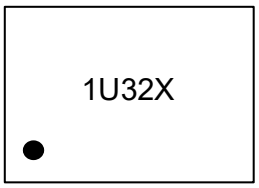
SYMBOL	MIN	NOM	MAX
A	-	-	1.10
A1	0.00	-	0.15
b	0.15	-	0.35
c	0.08	-	0.20
D	2.00	2.10	2.30
e	0.65BSC		
e1	1.30BSC		
E	2.15	2.30	2.50
E1	1.15	1.30	1.45
L	0.50REF		
L1	0.33REF		

Tape Information

SC70-5 (1.3mm × 2.1mm)



Marking Information



1U32 = Part Number
X = Tracking Number

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2022.11.11	Initial Version	Shi bo	Shi bo	Liu jiaying
1.1	2025-05-29	Add Packing Option	Yang xiaoxu	Yang xiaoxu	Liu jiaying
1.1.a	2025-09-19	Update Switching Waveforms	Yang xiaoxu	Yang xiaoxu	Liu jiaying
1.2	2025-10-15	Update Format	Wang anran	Yang xiaoxu	Liu jiaying